Coexistence of bulk superconductivity and charge density wave in Cu_xZrTe₃

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We report coexistence of bulk superconductivity and charge density wave (CDW) with superconducting critical temperature $T_c = 3.8$ K in Cu intercalated quasi-two-dimensional crystals of ZrTe₃. The Cu intercalation results in the expansion of the unit cell orthogonal to the Zr-Zr metal chains $(\hat{b}$ - axis) and partial filling of CDW energy bandgap without obvious shift of CDW transition temperature. \hat{b} - axis resistivity ρ_b is not related to CDW, and its dominant scattering mechanism for both ZrTe₃ and Cu_{0.05}ZrTe₃ is the electron - electron Umklapp scattering.

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Peierls instability results in the periodic modulation of electron density in solids and generates an energy bandgap at the Fermi surface (FS), which leads to insulating behavior in one-dimensional (1D) metal[1]. It can be observed as a charge density wave (CDW) superstructure in many low dimensional materials[2]. Superconductivity (SC), another instability of FS, will also generate a bandgap at FS, which results in a zero resistance. There is a view that SC and CDW orders can only compete with each other. NbSe₃, whose structure is composed of infinite NbSe₆ trigonal prismatic chains along the monoclinic b - axis, indures two CDW transition with CDW transition temperature $(T_{CDW}) = 145$ $K(T_1)$ and 59 $K(T_2)$. For example, High pressure continuously suppresses the second CDW transition and induces SC in quasi 1D NbSe₃[3]; The suppression of charge order in $Ba_{1-x}K_xBiO_3$ via doping brings out SC with highest $T_c \sim 30 \text{ K}[4]$; Recently, both Cu intercalation[5] and high pressure [6] in TiSe₂ continuously suppress the CDW order, and induce SC with a dome-like phase diagram, which strongly supports the competing view. However, CDW and SC can coexist with each other, like in 2H-NbSe₂ with $T_{CDW} = 33$ K and $T_c = 7.2$ K[2]. Angleresolved photoemission spectroscopy (ARPES) results of 2H-NbSe₂ show that maximized SC at points in momentum space are directly connected by the CDW ordering vector, demonstrating that charge order can boost SC in electron-phonon coupled system[7], which is in direct contrast to the previous view.

The interplay between CDW and SC is reminiscent of SC in heavy fermion and the cuprate oxide phase diagram when the magnetic order is tuned by pressure (P) or doping to $T \to 0$ [8–10]. Superconducting mechanism in such electronic systems is likely to be mediated by the magnetic fluctuations[11, 12]. Similarly, the dome-like structure of $T_c(x)$ and the pairing mechanism in $Cu_x TiSe_2$ is argued to stem from the type of quantum criticality related to fluctuations in CDW order[13]. Quantum phase transition is proposed to drive CDW order into a quantum nematic phase[14, 15]. On the other hand, the positive slope of the dome could be explained via the shift

of the Fermi level caused by Cu intercalation and the negative slope by the enhanced scattering for the high Cu concentration[16]. This is also supported by the evidence for a single gap s-wave order parameter, implying conventional mechanism despite the dome-like evolution of $T_c(x)[17]$. However, a dome-like structure of $T_c(P)$ was also discovered using P as a tuning parameter and suggesting that impurity effects may not be responsible for the dome closure[6].

Chalcogenide superconductors represent a weak coupling side of the smectic order, akin to stripe order in cuprates[14]. There is a mounting evidence that in such systems CDW states transform into Fermi liquid through an intermediate phase[18]. Therefore it is of interest to study the melting of CDW order parameter and possible nematic phases in a superconductor with highly related and tunable two dimensional electronic system.

ZrTe₃, as an trichalcogenide (MX₃, where M is the IV-VI transition-metal, and X is S, Se, Te), accommodates the quasi 2D ZrSe₃ type structure (shown in Fig. 1 (a))[19, 20], rather than the quasi 1D NbSe₃ type structure. The crystallographic \hat{b} - axis defines the direction of two sets of ZrTe₆ trigonal prismatic chains with the shortest Zr-Zr distance. ZrTe₃ endures a CDW transition at $T_{CDW} \sim 63$ K with a CDW wave vector $\overrightarrow{q} \equiv (\frac{1}{14}, 0, \frac{1}{3})[21, 22],$ and show corresponding hump anomaly on \widehat{a} - axis resistivity (ρ_a) and \widehat{c} - axis resistivity (ρ_c) around $T_{CDW}[21]$. The FS of ZrTe₃ contains one quasi 1D electron like sheet (pocket) of states of 5p Te chain origin that is responsible for CDW distortion and pseudogap formation at T \gg T_{CDW}[20, 23–25]. ZrTe₃ exhibits filamentary SC below 2 K with no diamagnetic response in H = 10 Oe[26]. The CDW and SC in ZrTe₃ exhibit rich and so called "competing" interplay under high pressure. With increasing P, the T_{CDW} initially increases below 2 GPa and then decreases up to the vanishing point $T_{CDW} \sim 40 \text{ K}$ at $\sim 5 \text{ GPa}[27]$; the T_c of filamentary SC decreases and vanish at $P \sim 0.5$ GPa, then a reentrant SC emerges at ~ 5 GPa with T_c rising monotonously up to 11 GPa ($T_c \sim 4.5$ K at 11 GPa). Keeping in mind that the FS of NbSe₃ mainly origi-

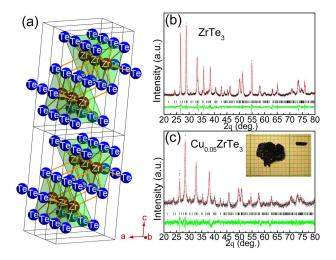


FIG. 1. (a)The crystal structure of ZrTe₃ with blue (brown) symbols for Te (Zr) atoms. Comparison of the observed (crosses) and calculated (solid line) powder X ray patterns of ZrTe₃ (b) and $Cu_{0.05}$ ZrTe₃ (c). The bars (black) correspond to the Bragg reflections and the lowest solid line is the difference between the observed and the calculated patterns.

nates from the Nb 3d electrons and dome-like structure of $T_c(P)$ in TiSe₂, ZrTe₃ provides a different opportunity to study the interplay between CDW and SC. Although intercalation attempts have been done in alkali atoms intercalated into ZrSe₃[28] and Cu intercalated ZrTe₃ via electrochemical method[29], no SC was discovered.

In this letter, we report coexistence of bulk SC and CDW in Cu intercalated ZrTe₃. The Cu intercalation results in the expansion of the unit cell orthogonal to \hat{b} - axis and partial filling of CDW bandgap without obvious shift of T_{CDW}. Anisotropic parameters of the superconducting state are presented. \hat{b} - axis resistivity (ρ_b) in the normal state is not related to CDW, and its dominant scattering mechanism for both ZrTe₃ and Cu_{0.05}ZrTe₃ is the electron - electron Umklapp scattering.

Single crystals of Cu_{0.05}ZrTe₃ and ZrTe₃ with typical size of $1 \times 3 \times 0.06 \text{ mm}^3$ (inset of Fig. 1(c)) elongated along the \hat{b} - axis were grown via iodine vapor transport method from pure elements sealed in an evacuated quartz tube. After 2 days pre-reacting at 973 K, the furnace gradient was kept between 1023 K and 923 K. Elemental analysis was performed by using energy-dispersive X-ray spectroscopy in an JEOL JSM-6500 scanning electron microscope. The Cu content is determined as the average of the different points on several crystals. Resistivity and magnetization were measured in Quantum Design PPMS-9 and MPMS-XL-5, respectively. The observed (Cu $K\alpha$ radiation of Rigaku Miniflex) and calculated[30] (Rietica software) powder X ray diffraction (XRD) patterns for $ZrTe_3$ and $Cu_{0.05}ZrTe_3$ are shown in Fig. 1 (b) and (c), respectively. Both materials can be indexed to the ZrTe₃, indicating that the Cu intercalation does not change the crystal structure. The unit cell refinement yields lat-

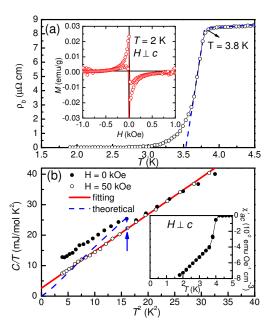


FIG. 2. (a) ρ_b (T) of Cu_{0.05}ZrTe₃ near T_c. Inset shows the M-H loop measured at T = 2 K for H \perp c. (b) (C/T) of Cu_{0.05}ZrTe₃ as a function of T² for H = 0 (solid circles) and H \parallel c = 50 kOe (open circles). Inset shows temperature dependence of χ'_{ac} . See text for details.

tice parameters a = 0.586(3) nm, b = 0.392(7) nm, c = 1.009(5) nm and β = 97.75(1)° for ZrTe₃, whereas for Cu_{0.05}ZrTe₃ we obtained a = 0.588(2) nm, b = 0.392(8) nm, c = 1.011(1) nm, and β = 97.75(1)°. The Cu intercalation leads to slight expansion of the \hat{a} and \hat{c} - axis parameters. It should be noted that Zr - Zr distances along the \hat{b} - axis chains are unchanged[20].

The onset of SC at T = 3.8 K can be observed in ρ_b , and the magnetization measurements confirm the SC in $\mathrm{Cu}_{0.05}\mathrm{ZrTe}_3$ (Fig. 2(a)). The shape of the magnetic hysteresis loop of is typical type - 2 inhomogeneous superconductors with some electromagnetic granularity (inset of Fig. 2(a)). This is in agreement with the transition from the temperature dependence of the real part of ac magnetic susceptibility (χ'_{ac}) of $\mathrm{Cu}_{0.05}\mathrm{ZrTe}_3$ (inset of Fig. 2(b)), and is similar to data in some high T_c cuprates and SmFeAsO_{0.85}F_{0.15}[31, 32]. Although the χ'_{ac} does not saturate down to 1.8 K, the large estimated superconducting volume fraction at T = 1.8 K ($4\pi\chi'_{ac} \sim 94\%$) reveals the bulk nature of SC in $\mathrm{Cu}_{0.05}\mathrm{ZrTe}_3$, as opposed to the pure material[26].

In order to obain the electron-phonon coupling constant λ , specific heat (C) of Cu_{0.05}ZrTe₃ was measured. Figure 2(b) depicts the specific heat divided by T (C/T) as a function of T² of Cu_{0.05}ZrTe₃ in H = 0 kOe and H||c = 50 kOe. Superconducting transition is suppressed in 50 kOe and from its linear fit (solid line depicted in Fig. 2 (b)) C/T = γ + β T² (γ T is electron contribution, and β T³ is phonon contribution), we obtain γ = 2.64 ±

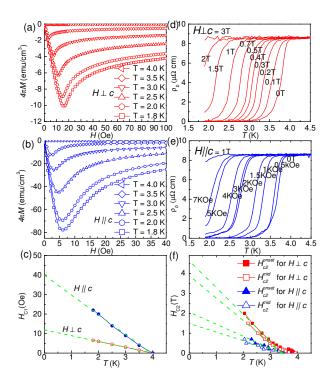


FIG. 3. Field dependence of magnetization of $Cu_{0.05}ZrTe_3$ for $H \perp c$ (a) and $H \parallel c$ (b). (c) Temperature dependence of H_{c1} for $H \perp c$ and $H \parallel c$. The dashed lines are the fitted lines. $\rho_b(T)$ of $Cu_{0.05}ZrTe_3$ for $H \perp c$ (d) and $H \parallel c$ (e). (f) $H_{c2}(T)$ onset and $H_{c2}(T)$ midpoint (see text) of $Cu_{0.05}ZrTe_3$.

 $0.12~\text{mJ/}~\text{mol}\text{K}^2$ and $\beta=1.21\pm0.01~\text{mJ/mol}\text{K}^4.$ A Debye temperature $\Theta_D=186(1)~\text{K}$ can be estimated using $\Theta_D=\big[\frac{1.944\times10^6\times N}{2}\big]^{1/3}$ where N is the number of atoms per formula unit. From the McMillan formula[33]

$$\lambda = \frac{\mu^* \ln(\frac{1.45T_C}{\Theta_D}) - 1.04}{1.04 + \ln(\frac{1.45T_C}{\Theta_D})(1 - 0.62\mu^*),} \tag{1}$$

we estimate the $\lambda \sim 0.68$ by assuming $\mu^* = 0.13$ for the Coulomb pseudopotential. This is a typical value of an intermediate coupling BCS superconductor. A specific heat jump $(\Delta C/\gamma T_c)$ can be observed around T = 4 K (marked by an arrow) confirming bulk SC. The dashed curve depicted in Fig.2(b) is the calculated result of the isotropic BCS gap with $2\Delta/k_BT_c = 3.53$ and $\Delta C/\gamma T_c = 1.43$. Although the C data in the superconducting state is not good due to the inhomogeneity, a $\Delta C/\gamma T_c$ larger than 1.43 can be estimated, suggesting the intermediate or strong e-p coupling.

The anisotropic properties of $Cu_{0.05}ZrTe_3$ in the superconducting state are investigated. Figures 3(a) and (b) show field dependence of magnetization of $Cu_{0.05}ZrTe_3$ measured at different temperatures for $H\perp c$ and $H\parallel c$. For $H\parallel c$, the H_{c1} is obtained using the demagnetization correction[34]. The $H_{c1}(T)$ shows almost linear realtion rather than $H_{c1} = H_{c1}(0)[1-(T/T_c)^2]$ temperature dependence for both field orientation (Fig. 3(c), dashed lines).

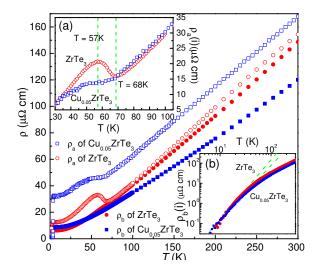


FIG. 4. Temperature dependence of ρ_a and ρ_b for ZrTe₃ and Cu_{0.05}ZrTe₃. (a) Temperature dependence of $\rho_a(i)$ for ZrTe₃ and Cu_{0.05}ZrTe₃; the peak (T = 57 K) and the valley (T = 68 K) of CDW anomaly in ZrTe₃ are marked with two dashed green lines. (b) Logarithmic plots of temperature dependence for $\rho_b(i)$ with fitting results (dashed green lines) for the Umklapp scattering process (see text).

Thus, we estimate $H_{c1}(0) = -0.693 \frac{\partial H_{c1}}{\partial T} T|_{T=T_c}$ from the Werthamer-Helfand-Hohenberg (WHH) equation[35] and we obtain 8.3(1) Oe ($H\perp c$) and 27.7(4) Oe ($H\parallel c$). Figures 3(d) and (e) show $\rho_b(T)$ of $Cu_{0.05}ZrTe_3$ measured in different fields for H⊥c and H||c. Figure 3(f) plots the temperature dependence of H_{c2}^{onset} (onset) and H_{c2}^{mid} (midpoint, 50% of ρ in the normal state). $H_{c2}(0)$ are estimated from the linear H_{c2} -T relation with WHH equation. Due to small variance in the in plane resistivity values[21], we assume that coherence lengths are isotropic in the \hat{a} - \hat{b} plane $(\xi_a \sim \xi_b = \xi_{ab})$ and we estimate[36] coherence leghts using $H_{c2}^c(0) = \Phi_0/(2\pi\xi_{ab}^2)$ and $H_{c2}^{ab}(0) = \Phi_0/(2\pi\xi_{ab}\xi_c)$ where Φ_0 is the flux quantum. The Ginzburg - Landau (GL) parameters κ_i and penetration depths are estimated from $H_{c2}^{i}(0)/H_{c1}^{i}(0) =$ $2\kappa_i^2/\ln \kappa_i$ (i = ab, c) and $\kappa_{ab}(0) = \lambda_{ab}(0)/\xi_c(0)$, respectively. Finally, from $H_c(0) = H_{c1}^{ab}(0)/\sqrt{2}\kappa_{ab}(0)$, we estimate the thermodynamic critical field. The anisotropy in obtained superconducting parameters can be approximately estimated from the anisotropic GL relation:

$$\gamma_{anis} = \sqrt{\Gamma} = \frac{H_{c2}^{ab}}{H_{c2}^c} = \frac{\xi_{ab}}{\xi_c} = \frac{\lambda_c}{\lambda_{ab}} = \frac{\kappa_{ab}}{\kappa_c} \sim \frac{H_{c1}^c}{H_{c1}^{ab}}$$
 (2)

where $\Gamma = \frac{m_c^*}{m_{ab}^*} = \frac{\rho_c}{\rho_{ab}}$ with the effective electron mass m_i^* along the i direction. The obtained mass tensor anisotropy $\Gamma \sim 7$ is comparable with the experimental resistivity ratio ~ 10 of ZrTe₃. [21] This points to small anisotropy in the gap function $\Delta(\mathbf{k}_F)$.[37] We list the obtained superconducting parameters in Table 1.

The in-plane anisotropic electronic transport proper-

TABLE I. Superconducting State Parameters for Cu_{0.05}ZrTe₃.

$Cu_{0.05}ZrTe_3$		$H_{c2}^i(0)$ (kOe)	$H_{c1}^i(0)$ (Oe)	$H_c(0)$ (Oe)	$\kappa_i(0)$	$\xi_i(0) \text{ (nm)}$	$\lambda_i(0) \text{ (nm)}$
i = ab	onset	32(4)	8.3(1)	240(30)	93(14)	16(1.2)	605(210)
	mid	27(3)		225(27)	85(11)	18(1.8)	570(184)
i = c	onset	13(2)	27.7(4)	330(50)	28(5)	6.5(1.3)	1490(420)
	mid	10(2)		295(50)	24(5)	6.7(1.3)	1539(477)

ties in the normal state of $Cu_0.05ZrTe_3$ and $ZrTe_3$ are studied. Fig. 4 shows the temperature dependence of ρ_a and ρ_b for ZrTe₃ and Cu_xZrTe₃, which indicates the absolute value of resistivity is quasi 2D for both of them. Since the residual resistivity (ρ_0) is related to the temperature independent defect scattering contribution, resistivity subtracted by ρ_0 ($\rho(i) = \rho - \rho_0$) can provide information about CDW or scattering mechanism. Compared with ZrTe₃ (Fig. 4 (inset,a)), a weaker anomaly below 68 K in $\rho_a(i)$ for Cu_{0.05}ZrTe₃ can be observed without a obvious shift. This is in contrast to shift of anomaly in ZrTe₃ under high pressure [27] and 1T-TiSe₂ by Cu intercalation or under high pressure [5, 6]. Since the resistivity anomaly (shown in Fig. 4 (inset, (a)) comes from of the reduction of DOS at FS due to the CDW bandgap, the weaker anomaly reflects that the CDW bandgap is partially filled via Cu intercalation. Meanwhile, the Cu intercalation has no significant effect on $\rho_b(i)$ (shown in Fig. 4 (inset, b)), even though the absolute values of resistivity are quasi 2D[21]. The scattering along the \hat{b} axis in the intercalated and the pure material are not related to the CDW. Linear relation of $\rho_b(i)$ shows that the dominant scattering channel along Zr-Zr metal chains in both materials is electron-electron Umklapp scattering (Fig. 4 (inset, b)), as expected for quasi one dimensional chains [38]. The Umklapp process will result in a $\rho(T) = \rho_0 + AT^n \text{ (where } 2 \leq n \leq 3) \text{ for } k_BT < (0.1)$ - 0.3) $|\delta|$, and a linear relation at high temperature for $k_BT > |\delta|[38]$. The parameter A is a constant and the $|\delta|$ is the typical inter-chain interaction energy. The power law temperature dependence is observed for T < 25 Kwith $n = 2.98 \pm 0.03$ and $n = 2.70 \pm 0.03$ for ZrTe₃ and Cu_{0.05}ZrTe₃, respectively (Fig. 4 (inset,b)). The estimated $|\delta|$ range is (100 - 250) K, which is consistent with the observed linear $\rho_b(T)$ above 180 K (Fig.4).

Generally speaking, anisotropic lattice expansion via Cu intercalation is different from the isotropic high pressure in ZrTe₃. It reminds us that uniaxial pressure in NbSe₃ results in different behavior with isotropic high pressures[39], and that most CDW bearing materials are anisotropic low dimensional system. Thus, the isotropic high pressure provides a combined effect in these materials, rather than a simple way of band widening as expected. It appears that ZrTe₃ is an good candidate for the systematic study of the interplay and of CDW and SC, and further spectroscopic measurements would be of

interest in order to unfold the details of the phonon mode softening and CDW melting as a function of Cu intercalation. Since SC is induced in another layered tritellurides TbTe₃ under high pressure[40], it is worthwhile to search SC by doping or intercalation in the family of CDW bearing layered rare earth tritellurides as well.

In summary, we have shown that Cu intercalation in ZrTe₃ results in the expansion of the lattice parameters in the \hat{a} - \hat{c} direction (orthogonal to Zr - Zr metal chains) and partial filling of the CDW energy gap. Bulk SC with $T_c=3.8$ K is discovered in Cu_{0.05}ZrTe₃, and its superconducting parameters are given. Along the Zr-Zr metal chains, electrical transport is not related to CDW, and the dominant dominant scattering mechanism is the electron - electron Umklapp scattering.

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